

Features

- Fast read access time – 45ns
- Low-power CMOS operation
 - 100µA max standby
 - 20mA max active at 5MHz
- JEDEC standard packages
 - 28-lead PDIP
 - 32-lead PLCC
- 5V ± 10% supply
- High-reliability CMOS technology
 - 2,000V ESD protection
 - 200mA latchup immunity
- Rapid programming algorithm – 100µs/byte (typical)
- CMOS- and TTL-compatible inputs and outputs
- Integrated product identification code
- Industrial and automotive temperature ranges
- Green (Pb/halide-free) packaging option

1. Description

The Atmel® AT27C512R is a low-power, high-performance, 524,288-bit, one-time programmable, read-only memory (OTP EPROM) organized as 64K by 8 bits. It requires only one 5V power supply in normal read mode operation. Any byte can be accessed in less than 45ns, eliminating the need for speed reducing WAIT states on high-performance microprocessor systems.

The Atmel scaled CMOS technology provides high speed, lower active power consumption, and significantly faster programming. Power consumption is typically only 8mA in active mode and less than 10µA in standby mode.

The AT27C512R is available in a choice of industry-standard, JEDEC-approved, one-time programmable (OTP) PDIP and PLCC packages. All devices feature two-line control (\overline{CE} , \overline{OE}) to give designers the flexibility to prevent bus contention.

With 64K byte storage capability, the AT27C512R allows firmware to be stored reliably and to be accessed by the system without the delays of mass storage media.

The AT27C512R has additional features to ensure high quality and efficient production use. The rapid programming algorithm reduces the time required to program the part and guarantees reliable programming. Programming time is typically only 100µs/byte. The integrated product identification code electronically identifies the device and manufacturer. This feature is used by industry standard programming equipment to select the proper programming algorithms and voltages.



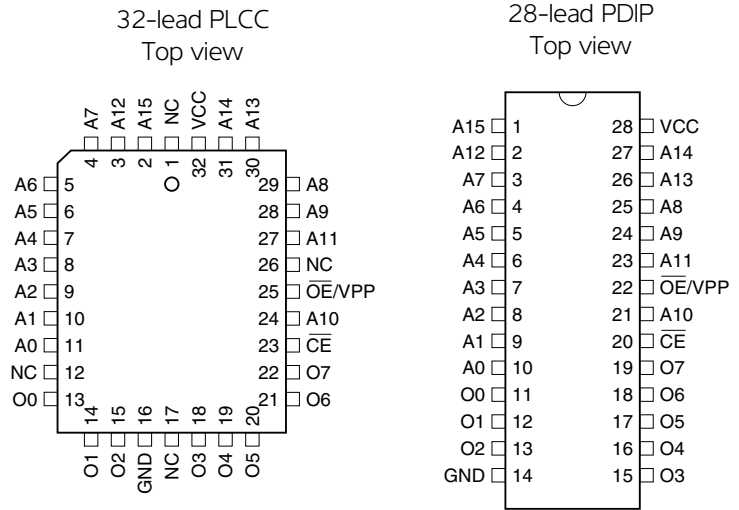
512K (64K x 8)
One-time
Programmable,
Read-only Memory

Atmel AT27C512R



2. Pin configurations

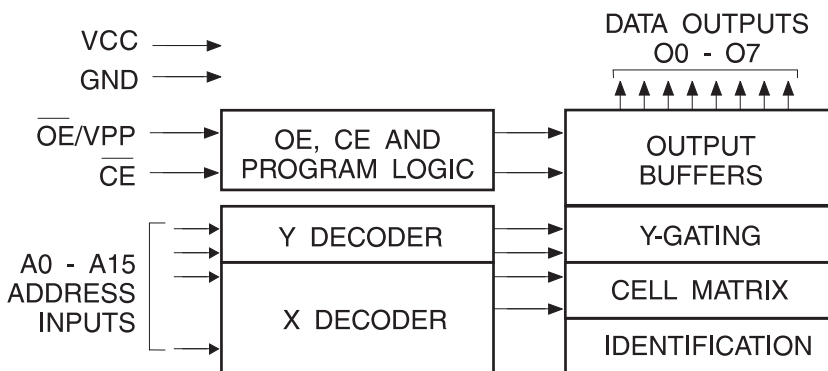
| Pin name | Function |
|---------------------|-------------------------------|
| A0 - A15 | Addresses |
| O0 - O7 | Outputs |
| \overline{CE} | Chip enable |
| \overline{OE}/VPP | Output enable/ Program supply |
| NC | No connect |



3. System considerations

Switching between active and standby conditions via the chip enable pin may produce transient voltage excursions. Unless accommodated by the system design, these transients may exceed datasheet limits, resulting in device nonconformance. At a minimum, a 0.1 μ F, high-frequency, low inherent inductance, ceramic capacitor should be utilized for each device. This capacitor should be connected between the V_{CC} and ground terminals of the device, as close to the device as possible. Additionally, to stabilize the supply voltage level on printed circuit boards with large EPROM arrays, a 4.7 μ F bulk electrolytic capacitor should be utilized, again connected between the V_{CC} and ground terminals. This capacitor should be positioned as close as possible to the point where the power supply is connected to the array.

Figure 3-1. Block diagram



4. Absolute maximum ratings*

| | |
|---|---------------------------------|
| Temperature under bias | -55°C to + 125°C |
| Storage temperature | -65°C to + 150°C |
| Voltage on any pin with respect to ground | -2.0V to + 7.0V ⁽¹⁾ |
| Voltage on A9 with respect to ground | -2.0V to + 14.0V ⁽¹⁾ |
| V _{pp} supply voltage with respect to ground | -2.0V to + 14.0V ⁽¹⁾ |

*NOTICE: Stresses beyond those listed under "Absolute maximum ratings" may cause permanent damage to the device. This is a stress rating only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note: 1. Minimum voltage is -0.6V DC, which may undershoot to -2.0V for pulses of less than 20ns. Maximum output pin voltage is V_{CC} + 0.75V DC, which may overshoot to +7.0V for pulses of less than 20ns.

5. DC and AC characteristics

Table 5-1. Operating modes

| Mode/Pin | \overline{CE} | \overline{OE}/V_{pp} | Ai | Outputs |
|---------------------------------------|-----------------|------------------------|---|---------------------|
| Read | V _{IL} | V _{IL} | Ai | D _{OUT} |
| Output disable | V _{IL} | V _{IH} | X ⁽¹⁾ | High Z |
| Standby | V _{IH} | X ⁽¹⁾ | X | High Z |
| Rapid program ⁽²⁾ | V _{IL} | V _{pp} | Ai | D _{IN} |
| PGM inhibit | V _{IH} | V _{pp} | X ⁽¹⁾ | High Z |
| Product identification ⁽⁴⁾ | V _{IL} | V _{IL} | A9 = V _H ⁽³⁾ A0 = V _{IH} or V _{IL} A1 - A15 = V _{IL} | Identification code |

Notes: 1. X can be V_{IL} or V_{IH}.
 2. Refer to programming characteristics.
 3. V_H = 12.0 ± 0.5V.
 4. Two identifier bytes may be selected. All Ai inputs are held low (V_{IL}), except A9, which is set to V_H, and A0, which is toggled low (V_{IL}) to select the manufacturer's identification byte and high (V_{IH}) to select the device code byte.

Table 5-2. DC and AC operating conditions for read operation

| | | Atmel AT27C512R | |
|------------------------|-------|-----------------|---------------|
| | | -45 | -70 |
| Operating temp. (case) | Ind. | -40°C - 85°C | -40°C - 85°C |
| | Auto. | | -40°C - 125°C |
| V _{CC} supply | | 5V ± 10% | 5V ± 10% |

Table 5-3. DC and operating characteristics for read operation

| Symbol | Parameter | Condition | Min | Max | Units | |
|----------|--------------------------------|---|-------|----------------|----------|---------|
| I_{LI} | Input load current | $V_{IN} = 0V$ to V_{CC} | Ind. | | ± 1 | μA |
| | | | Auto. | | ± 5 | μA |
| I_{LO} | Output leakage current | $V_{OUT} = 0V$ to V_{CC} | Ind. | | ± 5 | μA |
| | | | Auto. | | ± 10 | μA |
| I_{SB} | $V_{CC}^{(1)}$ standby current | I_{SB1} (CMOS), $\overline{CE} = V_{CC} \pm 0.3V$ | | 100 | μA | |
| | | I_{SB2} (TTL), $\overline{CE} = 2.0$ to $V_{CC} + 0.5V$ | | 1 | mA | |
| I_{CC} | V_{CC} active current | $f = 5MHz$, $I_{OUT} = 0mA$, $\overline{CE} = V_{IL}$ | | 20 | mA | |
| V_{IL} | Input low voltage | | -0.6 | 0.8 | V | |
| V_{IH} | Input high voltage | | 2.0 | $V_{CC} + 0.5$ | V | |
| V_{OL} | Output low voltage | $I_{OL} = 2.1mA$ | | 0.4 | V | |
| V_{OH} | Output high voltage | $I_{OH} = -400\mu A$ | 2.4 | | V | |

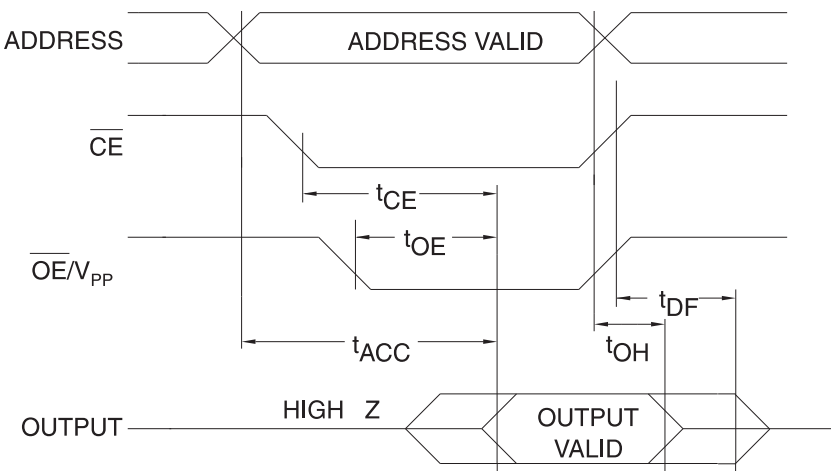
Note: 1. V_{CC} must be applied simultaneously with or before \overline{OE}/V_{pp} , and removed simultaneously with or after \overline{OE}/V_{pp} .

Table 5-4. AC characteristics for read operation

| Symbol | Parameter | Condition | Atmel AT27C512R | | | | Units |
|-----------------|--|---|-----------------|-----|-----|-----|-------|
| | | | -45 | | -70 | | |
| | | | Min | Max | Min | Max | |
| $t_{ACC}^{(1)}$ | Address to output delay | $\overline{CE} = \overline{OE}/V_{pp} = V_{IL}$ | | 45 | | 70 | ns |
| $t_{CE}^{(1)}$ | \overline{CE} to output delay | $\overline{OE}/V_{pp} = V_{IL}$ | | 45 | | 70 | ns |
| $t_{OE}^{(1)}$ | \overline{OE}/V_{pp} to output delay | $\overline{CE} = V_{IL}$ | | 20 | | 30 | ns |
| $t_{DF}^{(1)}$ | \overline{OE}/V_{pp} or \overline{CE} high to output float, whichever occurred first | | | 20 | | 25 | ns |
| t_{OH} | Output hold from address, \overline{CE} or \overline{OE}/V_{pp} , whichever occurred first | | 7 | | 7 | | ns |

Note: 1. See AC waveforms for read operation.

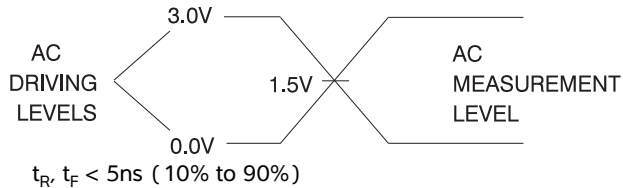
Figure 5-1. AC waveforms for read operation⁽¹⁾



- Notes:
1. Timing measurement reference level is 1.5V for -45 devices. Input AC drive levels are $V_{IL} = 0.0V$ and $V_{IH} = 3.0V$. Timing measurement reference levels for all other speed grades are $V_{OL} = 0.8V$ and $V_{OH} = 2.0V$. Input AC drive levels are $V_{IL} = 0.45V$ and $V_{IH} = 2.4V$.
 2. \overline{OE}/V_{pp} may be delayed up to $t_{CE} - t_{OE}$ after the falling edge of \overline{CE} without impact on t_{CE} .
 3. \overline{OE}/V_{pp} may be delayed up to $t_{ACC} - t_{OE}$ after the address is valid without impact on t_{ACC} .
 4. This parameter is only sampled, and is not 100% tested.
 5. Output float is defined as the point when data is no longer driven.

Figure 5-2. Input test waveforms and measurement levels

For -45 devices only:



For -70 devices:

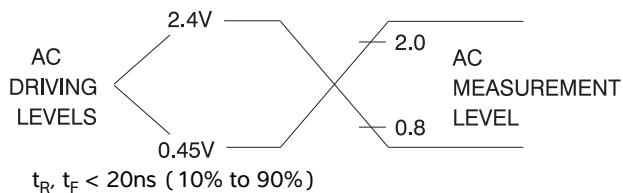
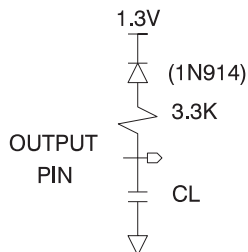


Figure 5-3. Output test load



Note: 1. $C_L = 100\text{pF}$ including jig capacitance, except for the -45 devices, where $C_L = 30\text{pF}$.

Table 5-5. Pin capacitance

$f = 1\text{MHz}$, $T = 25^\circ\text{C}$ ⁽¹⁾

| Symbol | Typ | Max | Units | Conditions |
|-----------|-----|-----|-------|-----------------------|
| C_{IN} | 4 | 6 | pF | $V_{IN} = 0\text{V}$ |
| C_{OUT} | 8 | 12 | pF | $V_{OUT} = 0\text{V}$ |

Note: 1. Typical values for nominal supply voltage. This parameter is only sampled, and is not 100% tested.

Figure 5-4. Programming Waveforms ⁽¹⁾



- Notes:
1. The input timing reference is 0.8V for V_{IL} and 2.0V for V_{IH} .
 2. t_{OE} and t_{DFP} are characteristics of the device, but must be accommodated by the programmer.

Table 5-6. DC programming characteristics

 $T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $\overline{\text{OE}}/V_{PP} = 13.0 \pm 0.25\text{V}$

| Symbol | Parameter | Test conditions | Limits | | Units |
|-----------|--|---------------------------------|--------|--------------|---------------|
| | | | Min | Max | |
| I_{LI} | Input load current | $V_{IN} = V_{IL}, V_{IH}$ | | ± 10 | μA |
| V_{IL} | Input low level | | -0.6 | 0.8 | V |
| V_{IH} | Input high level | | 2.0 | $V_{CC} + 1$ | V |
| V_{OL} | Output low voltage | $I_{OL} = 2.1\text{mA}$ | | 0.4 | V |
| V_{OH} | Output high voltage | $I_{OH} = -400\mu\text{A}$ | 2.4 | | V |
| I_{CC2} | V_{CC} supply current (program and verify) | | | 25 | mA |
| I_{PP2} | $\overline{\text{OE}}/V_{PP}$ current | $\overline{\text{CE}} = V_{IL}$ | | 25 | mA |
| V_{ID} | A9 product identification voltage | | 11.5 | 12.5 | V |

Table 5-7. AC programming characteristics

 $T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.5 \pm 0.25\text{V}$, $\overline{\text{OE}}/V_{PP} = 13.0 \pm 0.25\text{V}$

| Symbol | Parameter | Test conditions ⁽¹⁾ | Limits | | Units |
|-----------|--|--|--------|-----|---------------|
| | | | Min | Max | |
| t_{AS} | Address setup time | Input rise and fall times (10% to 90%) 20ns | 2 | | μs |
| t_{OES} | $\overline{\text{OE}}/V_{PP}$ setup time | | 2 | | μs |
| t_{OEH} | $\overline{\text{OE}}/V_{PP}$ hold time | | 2 | | μs |
| t_{DS} | Data setup time | | 2 | | μs |
| t_{AH} | Address hold time | Input pulse levels 0.45V to 2.4V | 0 | | μs |
| t_{DH} | Data hold time | | 2 | | μs |
| t_{DFP} | $\overline{\text{CE}}$ high to output float delay ⁽²⁾ | Input timing reference level | 0 | 130 | ns |
| t_{VCS} | V_{CC} setup time | 0.8V to 2.0V | 2 | | μs |
| t_{PW} | $\overline{\text{CE}}$ program pulse width ⁽³⁾ | Output timing reference level 0.8V to 2.0V | 95 | 105 | μs |
| t_{DV} | Data valid from $\overline{\text{CE}}$ ⁽²⁾ | | | 1 | μs |
| t_{VR} | $\overline{\text{OE}}/V_{PP}$ recovery time | | 2 | | μs |
| t_{PRT} | $\overline{\text{OE}}/V_{PP}$ pulse rise time during programming | | 50 | | ns |

- Notes:
- V_{CC} must be applied simultaneously with or before $\overline{\text{OE}}/V_{PP}$ and removed simultaneously with or after $\overline{\text{OE}}/V_{PP}$.
 - This parameter is only sampled, and is not 100% tested. Output float is defined as the point where data is no longer driven. See timing diagram.
 - Program pulse width tolerance is $100\mu\text{sec} \pm 5\%$.

Table 5-8. The Atmel AT27C512R integrated product identification code

| Codes | Pins | | | | | | | | | Hex data |
|--------------|------|----|----|----|----|----|----|----|----|----------|
| | A0 | O7 | O6 | O5 | O4 | O3 | O2 | O1 | O0 | |
| Manufacturer | 0 | 0 | 0 | 0 | 1 | 1 | 1 | 1 | 0 | 1E |
| Device type | 1 | 0 | 0 | 0 | 0 | 1 | 1 | 0 | 1 | 0D |

6. Rapid programming algorithm

A $100\mu\text{s}$ $\overline{\text{CE}}$ pulse width is used to program. The address is set to the first location. V_{CC} is raised to 6.5V and $\overline{\text{OE}}/V_{\text{PP}}$ is raised to 13.0V. Each address is first programmed with one $100\mu\text{s}$ $\overline{\text{CE}}$ pulse without verification. Then a verification/reprogramming loop is executed for each address. In the event a byte fails to pass verification, up to 10 successive $100\mu\text{s}$ pulses are applied with a verification after each pulse. If the byte fails to verify after 10 pulses have been applied, the part is considered failed. After the byte verifies properly, the next address is selected until all have been checked. $\overline{\text{OE}}/V_{\text{PP}}$ is then lowered to V_{IL} and V_{CC} to 5.0V. All bytes are read again and compared with the original data to determine if the device passes or fails.

Figure 6-1. Rapid programming algorithm



7. Ordering information

Green package (Pb/halide-free)

| t _{ACC} (ns) | I _{CC} (mA) | | Atmel ordering code | Package | Lead finish | Operation range |
|--------------------------|----------------------|---------|---------------------|---------|-------------|-------------------------------|
| | Active | Standby | | | | |
| 45 | 20 | 0.1 | AT27C512R-45JU | 32J | Matte tin | Industrial (-40°C to 85°C) |
| | | | AT27C512R-45PU | 28P6 | Matte tin | |
| 70 | 20 | 0.1 | AT27C512R-70JU | 32J | Matte tin | Industrial (-40°C to 85°C) |
| | | | AT27C512R-70PU | 28P6 | Matte tin | |

| Package type | |
|--------------|---|
| 32J | 32-lead, plastic, J-leaded chip carrier (PLCC) |
| 28P6 | 28-lead, 0.600" wide, plastic, dual inline package (PDIP) |

8. Packaging information

32J – PLCC



28P6 – PDIP



COMMON DIMENSIONS
(Unit of Measure = mm)

| SYMBOL | MIN | NOM | MAX | NOTE |
|--------|-----------|-----|--------|--------|
| A | - | - | 4.826 | |
| A1 | 0.381 | - | - | |
| D | 36.703 | - | 37.338 | Note 2 |
| E | 15.240 | - | 15.875 | |
| E1 | 13.462 | - | 13.970 | Note 2 |
| B | 0.356 | - | 0.559 | |
| B1 | 1.041 | - | 1.651 | |
| L | 3.048 | - | 3.556 | |
| C | 0.203 | - | 0.381 | |
| eB | 15.494 | - | 17.526 | |
| e | 2.540 TYP | | | |

- Notes:
1. This package conforms to JEDEC reference MS-011, variation AB
 2. Dimensions D and E1 do not include mold flash or protrusion
mold flash or protrusion shall not exceed 0.25mm (0.010")

09/28/01



Package drawing contact:
packagedrawings@atmel.com

TITLE

28P6, 28-lead (0.600"/15.24mm wide) plastic dual inline package (PDIP)

DRAWING NO.

28P6

REV.

B





9. Revision history

| Doc. rev. | Date | Comments |
|-----------|---------|--|
| 0015Q | 10/2011 | Correct pinout note |
| 0015P | 04/2011 | Remove TSOP and SOIC packages Add lead finish to ordering information |
| 0015O | 12/2007 | |



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Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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